NSN 5962-01-226-6270

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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 incl	nes and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power I	Dissipation Rating:
794.0 milliwatts	
Operating Tempu	ature Range:
-55.0/+125.0 degre	es celsius
Storage Tempurat	ure Range:
65.0/+150.0 degre	es celsius
End Application:	
An/bps14to15e	
Features Provided	
Hermetically sealed	and burn in and programmable and bipolar and schottky
Inclosure Material	:
Ceramic	
nclosure Configu	ration:
Dual-in-line	
Output Logic Forr	n:
Transistor-transisto	r logic
nput Circuit Patte	rn:
10 input	
Case Outline Sou	ce And Designator:
D-2 mil-m-38510	
Terminal Surface	Treatment:
Solder	
Voltage Rating Ar	d Type Per Characteristic:
0.5 volts power so	purce and 7.0 volts power source
Time Rating Per C	hacteristic:
85.00 nanosecond	propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Ty	/pe:
Prom	
Memory Capacity	
Unknown	
Test Data Docume	ent:
	standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type An	
16 printed circuit	-
Shelf Life:	

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

